MOSFETs Silicon N-channel MOS (U-MOSⅧ-H)

TPH4R50ANH

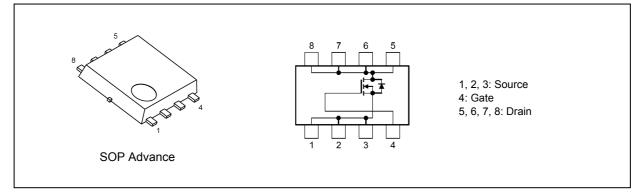
1. Applications

- DC-DC Converters
- Switching Voltage Regulators
- Motor Drivers

2. Features

- (1) Small, thin package
- (2) High-speed switching
- (3) Small gate charge: $Q_{SW} = 22 \text{ nC}$ (typ.)
- (4) Low drain-source on-resistance: $R_{DS(ON)} = 3.7 \text{ m}\Omega \text{ (typ.)} (V_{GS} = 10 \text{ V})$
- (5) Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 100 \ V)$
- (6) Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1.0 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) (T_a = 25°C unless otherwise specified)

Characteris	Symbol	Rating	Unit		
Drain-source voltage			V _{DSS}	100	V
Gate-source voltage			V _{GSS}	±20	
Drain current (DC)	(Silicon limit)	(Note 1), (Note 2)	I _D	93	A
Drain current (DC)	(T _c = 25°C)	(Note 1)	Ι _D	60	
Drain current (pulsed)	(t = 1 ms)	(Note 1)	I _{DP}	200	
Power dissipation	(T _c = 25°C)		PD	78	W
Power dissipation	(t = 10 s)	(Note 3)	PD	2.8	W
Power dissipation	(t = 10 s)	(Note 4)	PD	1.6	W
Single-pulse avalanche energy		(Note 5)	E _{AS}	274	mJ
Avalanche current			I _{AR}	60	A
Channel temperature			T _{ch}	150	°C
Storage temperature			T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production

5. Thermal Characteristics

Characteristics				Max	Unit
Channel-to-case thermal resistance	(T _c = 25°C)		R _{th(ch-c)}	1.60	°C/W
Channel-to-ambient thermal resistance	(t = 10 s)	(Note 3)	R _{th(ch-a)}	44.6	°C/W
Channel-to-ambient thermal resistance	(t = 10 s)	(Note 4)	R _{th(ch-a)}	78.1	°C/W

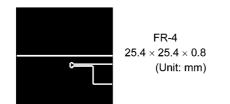
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: Limited by silicon chip capability. Package limit is 60 A.

Note 3: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 4: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 5: V_DD = 60 V, T_ch = 25°C (initial), L = 0.082 mH, R_G = 1.0 $\Omega,$ I_AR = 60 A



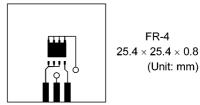


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a) Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

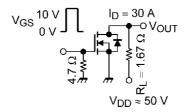
6. Electrical Characteristics

6.1. Static Characteristics (Ta = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V	_	_	±0.1	μA
Drain cut-off current	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V	_		10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	100	—	—	V
	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	65	_	_	
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 1.0 mA	2.0	_	4.0	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 30 A	_	3.7	4.5	mΩ

6.2. Dynamic Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 50 V, V _{GS} = 0 V, f = 1 MHz		4000	5200	pF
Reverse transfer capacitance	C _{rss}		_	31	63	
Output capacitance	C _{oss}			700	_	
Gate resistance	rg	-		1.0	1.5	Ω
Switching time (rise time)	t _r	See Figure 6.2.1.	_	9.6	—	ns
Switching time (turn-on time)	t _{on}]		25	_	
Switching time (fall time)	t _f			13	_	
Switching time (turn-off time)	t _{off}]	_	52	_	



 $Duty \le 1\%, \ t_w = 10 \ \mu s$ Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

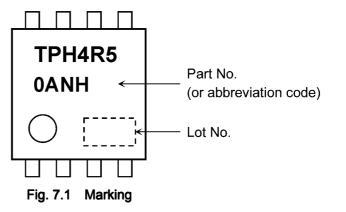
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 50 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 60 \text{ A}$	—	58	—	nC
Gate-source charge 1	Q _{gs1}			22	_	
Gate-drain charge	Q _{gd}		_	12	_	
Gate switch charge	Q _{SW}			22	_	

6.4. Source-Drain Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

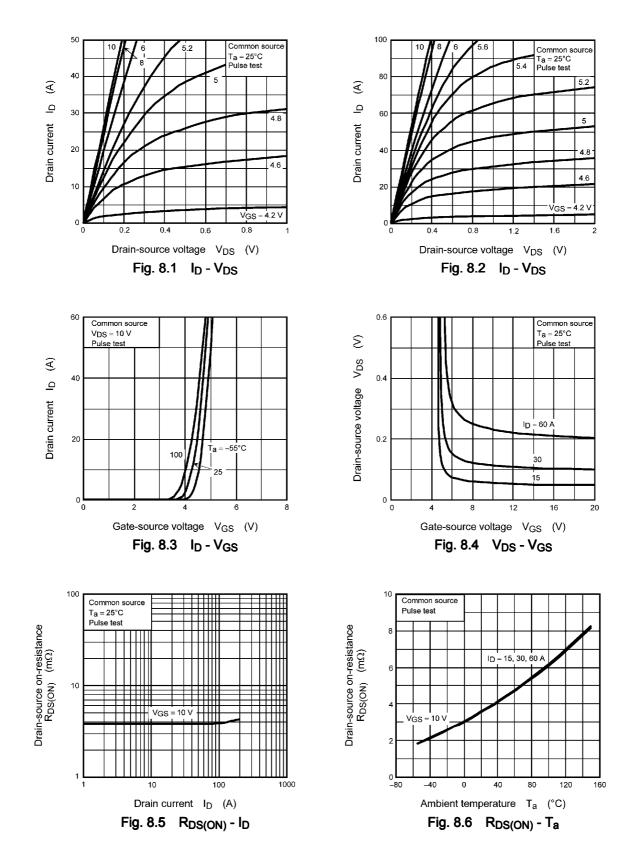
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (Note	6) I _{DRP}	_	_	_	200	А
Diode forward voltage	V _{DSF}	I _{DR} = 60 A, V _{GS} = 0 V	_	—	-1.2	V

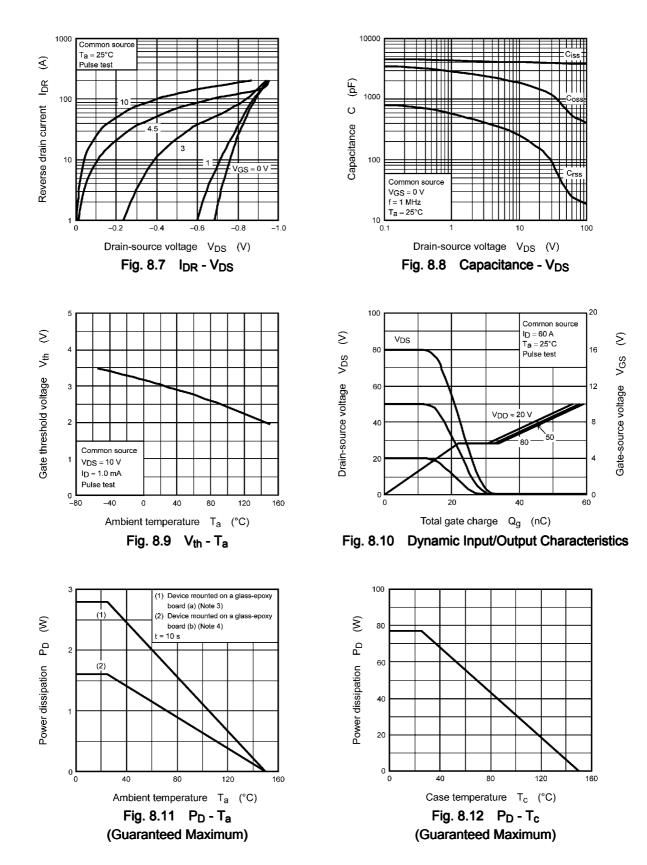
Note 6: Ensure that the channel temperature does not exceed 150°C.

7. Marking



8. Characteristics Curves (Note)





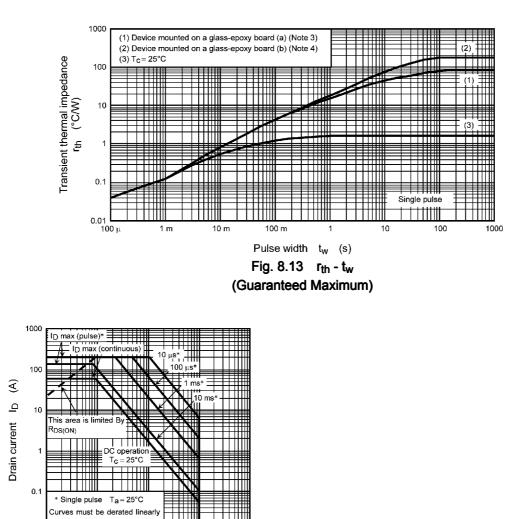


with increase in temperature

10

Drain-source voltage V_{DS} (V) Fig. 8.14 Safe Operating Area (Guaranteed Maximum)

0.01 C



(DSS max

100

1000

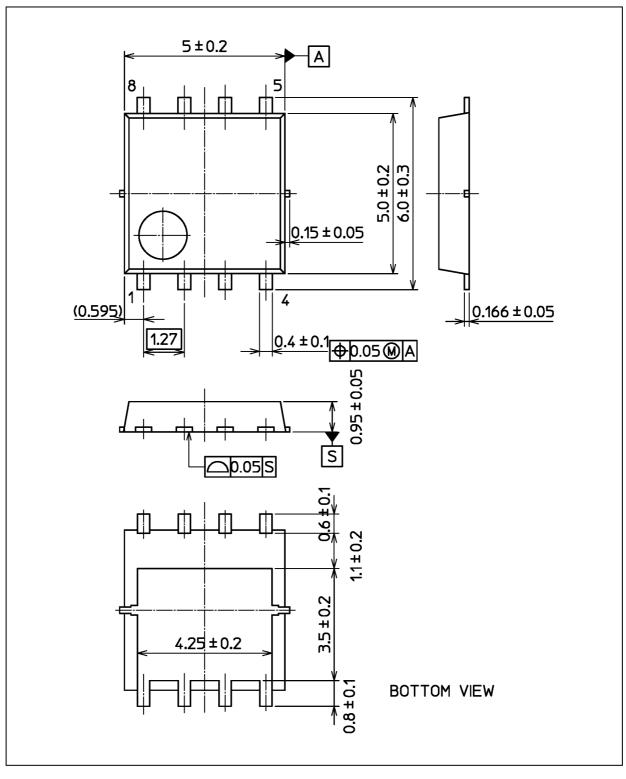
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



TPH4R50ANH

Package Dimensions

Unit: mm



Weight: 0.069 g (typ.)

Package Name(s)

TOSHIBA: 2-5Q1S

Nickname: SOP Advance

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